Dual non-inverting Schmitt trigger Rev. 2 — 2 February 2022

### 1. General description

The 74HC2G17; 74HCT2G17 are dual buffers with Schmitt-trigger inputs. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ . Schmitt trigger inputs transform slowly changing input signals into sharply defined jitter-free output signals.

### 2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- High noise immunity
- Unlimited input rise and fall times
- Balanced propagation delays
- Input levels:
  - For 74HC2G17: CMOS level
  - For 74HCT2G17: TTL level
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
  - Complies with JEDEC standards:
  - JESD8C (2.7 V to 3.6 V)
  - JESD7A (2.0 V to 6.0 V)
- ESD protection:
  - HBM JESD22-A114-D exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

### 3. Applications

- · Wave and pulse shaper for highly noisy environments
- Astable multivibrators
- Monostable multivibrators

### 4. Ordering information

#### Table 1. Ordering information

| Type number | Package                |        |   |          |  |  |  |
|-------------|------------------------|--------|---|----------|--|--|--|
|             | Temperature range Name |        | Description   | Version  |  |  |  |
| 74HC2G17GW  | -40 °C to +125 °C      | TSSOP6 | plastic thin shrink small outline package; 6 leads; | SOT363-2 |  |  |  |
| 74HCT2G17GW |                        |        | body width 1.25 mm                                  |          |  |  |  |
| 74HC2G17GV  | -40 °C to +125 °C      | SC-74; | plastic surface-mounted package; 6 leads            | SOT457   |  |  |  |
| 74HCT2G17GV |                        | TSOP6  |   |          |  |  |  |

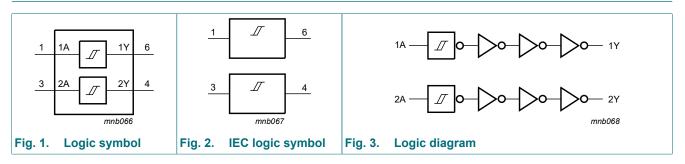
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### 5. Marking

| Table 2. Marking |                 |  |  |  |  |
|------------------|-----------------|--|--|--|--|
| Type number      | Marking code[1] |  |  |  |  |
| 74HC2G17GW       | HV              |  |  |  |  |
| 74HCT2G17GW      | TV              |  |  |  |  |
| 74HC2G17GV       | HV              |  |  |  |  |
| 74HCT2G17GV      | TV              |  |  |  |  |

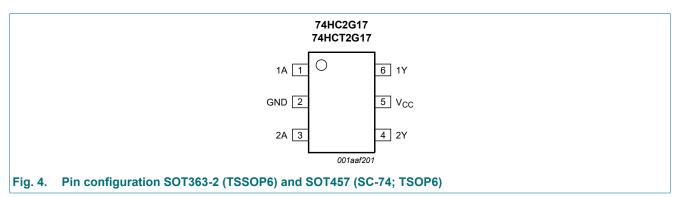
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 6. Functional diagram



# 7. Pinning information

### 7.1. Pinning



### 7.2. Pin description

| Table 3. Pin description |     |                |  |  |  |  |
|--------------------------|-----|----------------|--|--|--|--|
| Symbol                   | Pin | Description    |  |  |  |  |
| 1A                       | 1   | data input     |  |  |  |  |
| GND                      | 2   | ground (0 V)   |  |  |  |  |
| 2A                       | 3   | data input     |  |  |  |  |
| 2Y                       | 4   | data output    |  |  |  |  |
| V <sub>CC</sub>          | 5   | supply voltage |  |  |  |  |
| 1Y                       | 6   | data output    |  |  |  |  |

74HC\_HCT2G17

**Product data sheet** 

### 8. Functional description

#### Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

| Input | Output |
|-------|--------|
| nA    | nY     |
| L     | L      |
| Н     | Н      |

### 9. Limiting values

#### Table 5. Limiting values

[2]

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions   |     | Min  | Max  | Unit |
|------------------|-------------------------|--|-----|------|------|------|
| V <sub>CC</sub>  | supply voltage          |  |     | -0.5 | +7.0 | V    |
| I <sub>IK</sub>  | input clamping current  | $V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V | [1] | -    | ±20  | mA   |
| I <sub>OK</sub>  | output clamping current | $V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V | [1] | -    | ±20  | mA   |
| lo               | output current          | $V_{O}$ = -0.5 V to $V_{CC}$ + 0.5 V                       | [1] | -    | ±25  | mA   |
| I <sub>CC</sub>  | supply current          |  | [1] | -    | 50   | mA   |
| I <sub>GND</sub> | ground current          |  | [1] | -    | -50  | mA   |
| T <sub>stg</sub> | storage temperature     |  |     | -65  | +150 | °C   |
| P <sub>tot</sub> | total power dissipation |  | [2] | -    | 250  | mW   |

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT363-2 (TSSOP6) package: P<sub>tot</sub> derates linearly with 3.7 mW/K above 83 °C.

For SOT457 (SC-74; TSOP6) package: Ptot derates linearly with 4.1 mW/K above 89 °C.

### 10. Recommended operating conditions

#### Table 6. Recommended operating conditions Symbol Parameter Conditions Min Unit Тур Max 74HC2G17 V<sub>CC</sub> 2.0 5.0 6.0 v supply voltage V VI input voltage 0 V<sub>CC</sub> - $V_{CC}$ v Vo 0 output voltage °C -40 +125 Tamb ambient temperature +25 74HCT2G17 V<sub>CC</sub> supply voltage 4.5 5.0 5.5 V $V_{CC}$ V VI input voltage 0 \_ v Vo output voltage 0 -V<sub>CC</sub> °C ambient temperature -40 +25 +125 Tamb

# **11. Static characteristics**

#### Table 7. Static characteristics for 74HC2G17

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol               | Parameter                 | Conditions   | Min  | Тур  | Max  | Unit |
|----------------------|---------------------------|--|------|------|------|------|
| T <sub>amb</sub> = 2 | 25 °C                     | · · · ·  |      |      |      |      |
| V <sub>OH</sub>      | HIGH-level output voltage | $V_{I} = V_{T+}$ or $V_{T-}$   |      |      |      |      |
|                      |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V                               | 1.9  | 2.0  | -    | V    |
|                      |                           | $I_{O}$ = -20 µA; $V_{CC}$ = 4.5 V   | 4.4  | 4.5  | -    | V    |
|                      |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V                               | 5.9  | 6.0  | -    | V    |
|                      |                           | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V                              | 4.18 | 4.32 | -    | V    |
|                      |                           | I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V                              | 5.68 | 5.81 | -    | V    |
| V <sub>OL</sub>      | LOW-level output voltage  | $V_{I} = V_{T+}$ or $V_{T-}$   |      |      |      |      |
|                      |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V                                | -    | 0    | 0.1  | V    |
|                      |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V                                | -    | 0    | 0.1  | V    |
|                      |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V                                | -    | 0    | 0.1  | V    |
|                      |                           | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V                               | -    | 0.15 | 0.26 | V    |
|                      |                           | I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V                               | -    | 0.16 | 0.26 | V    |
| l <sub>l</sub>       | input leakage current     | $V_{I}$ = GND or $V_{CC}$ ; $V_{CC}$ = 6.0 V                                   | -    | -    | ±0.1 | μA   |
| I <sub>CC</sub>      | supply current            | $V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$<br>$V_{CC} = 6.0 \text{ V}$ | -    | -    | 1.0  | μA   |
| CI                   | input capacitance         |  | -    | 2.0  | -    | pF   |
| T <sub>amb</sub> = - | 40 °C to +85 °C           |  |      |      |      |      |
| V <sub>OH</sub>      | HIGH-level output voltage | $V_{I} = V_{T+}$ or $V_{T-}$   |      |      |      |      |
|                      |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V                               | 1.9  | -    | -    | V    |
|                      |                           | $I_{O}$ = -20 µA; $V_{CC}$ = 4.5 V   | 4.4  | -    | -    | V    |
|                      |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V                               | 5.9  | -    | -    | V    |
|                      |                           | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V                              | 4.13 | -    | -    | V    |
|                      |                           | I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V                              | 5.63 | -    | -    | V    |
| V <sub>OL</sub>      | LOW-level output voltage  | $V_I = V_{T+}$ or $V_{T-}$   |      |      |      |      |
|                      |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V                                | -    | -    | 0.1  | V    |
|                      |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V                                | -    | -    | 0.1  | V    |
|                      |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V                                | -    | -    | 0.1  | V    |
|                      |                           | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V                               | -    | -    | 0.33 | V    |
|                      |                           | I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V                               | -    | -    | 0.33 | V    |
| l <sub>l</sub>       | input leakage current     | $V_I$ = GND or $V_{CC}$ ; $V_{CC}$ = 6.0 V                                     | -    | -    | ±1.0 | μA   |
| I <sub>CC</sub>      | supply current            | $V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A;<br>$V_{CC}$ = 6.0 V                     | -    | -    | 10.0 | μA   |

#### Dual non-inverting Schmitt trigger

| Symbol                | Parameter                 | Conditions   | Min | Тур | Max  | Unit |
|-----------------------|---------------------------|--|-----|-----|------|------|
| T <sub>amb</sub> = -4 | 40 °C to +125 °C          | I  |     | 1   |      |      |
| V <sub>OH</sub>       | HIGH-level output voltage | $V_I = V_{T+}$ or $V_{T-}$                                 |     |     |      |      |
|                       |                           | $I_{O}$ = -20 µA; $V_{CC}$ = 2.0 V                         | 1.9 | -   | -    | V    |
|                       |                           | $I_{O}$ = -20 µA; $V_{CC}$ = 4.5 V                         | 4.4 | -   | -    | V    |
|                       |                           | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V           | 5.9 | -   | -    | V    |
|                       |                           | $I_{O}$ = -4.0 mA; $V_{CC}$ = 4.5 V                        | 3.7 | -   | -    | V    |
|                       |                           | I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V          | 5.2 | -   | -    | V    |
| V <sub>OL</sub>       | LOW-level output voltage  | $V_{I} = V_{T+}$ or $V_{T-}$                               |     |     |      |      |
|                       |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V            | -   | -   | 0.1  | V    |
|                       |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V            | -   | -   | 0.1  | V    |
|                       |                           | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V            | -   | -   | 0.1  | V    |
|                       |                           | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V           | -   | -   | 0.4  | V    |
|                       |                           | I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V           | -   | -   | 0.4  | V    |
| l <sub>l</sub>        | input leakage current     | $V_I$ = GND or $V_{CC}$ ; $V_{CC}$ = 6.0 V                 | -   | -   | ±1.0 | μA   |
| I <sub>CC</sub>       | supply current            | $V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A;<br>$V_{CC}$ = 6.0 V | -   | -   | 20.0 | μA   |

#### Table 8. Static characteristics for 74HCT2G17

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol               | Parameter                 | Conditions   | Min  | Тур  | Max  | Unit |
|----------------------|---------------------------|--|------|------|------|------|
| T <sub>amb</sub> = 2 | 25 °C                     |  | I    |      |      |      |
| V <sub>ОН</sub>      | HIGH-level output voltage | $V_{I} = V_{T+} \text{ or } V_{T-}; V_{CC} = 4.5 \text{ V}$  |      |      |      |      |
| 0.1                  |                           | I <sub>O</sub> = -20 μA  | 4.4  | 4.5  | -    | V    |
|                      |                           | I <sub>O</sub> = -4.0 mA   | 4.18 | 4.32 | -    | V    |
| V <sub>OL</sub>      | LOW-level output voltage  | $V_{I} = V_{T+} \text{ or } V_{T-}; V_{CC} = 4.5 \text{ V}$  |      |      |      |      |
|                      |                           | I <sub>O</sub> = -20 μA  | -    | 0    | 0.1  | V    |
|                      |                           | I <sub>O</sub> = -4.0 mA   | -    | 0.15 | 0.26 | V    |
| l <sub>l</sub>       | input leakage current     | $V_{I}$ = GND or $V_{CC}$ ; $V_{CC}$ = 5.5 V   | -    | -    | ±0.1 | μA   |
| I <sub>CC</sub>      | supply current            | $V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$<br>$V_{CC} = 5.5 \text{ V}$                       | -    | -    | 1.0  | μA   |
| ΔI <sub>CC</sub>     | additional supply current | $V_{I} = V_{CC} - 2.1 V;$<br>$V_{CC} = 4.5 V \text{ to } 5.5 V; I_{O} = 0 \text{ A}$                 | -    | -    | 300  | μA   |
| CI                   | input capacitance         |  | -    | 2.0  | -    | pF   |
| T <sub>amb</sub> = - | 40 °C to +85 °C           |  |      |      |      |      |
| V <sub>ОН</sub>      | HIGH-level output voltage | $V_{I} = V_{T+} \text{ or } V_{T-}; V_{CC} = 4.5 \text{ V}$  |      |      |      |      |
|                      |                           | I <sub>O</sub> = -20 μA  | 4.4  | -    | -    | V    |
|                      |                           | I <sub>O</sub> = -4.0 mA   | 4.13 | -    | -    | V    |
| V <sub>OL</sub>      | LOW-level output voltage  | $V_{I} = V_{T+} \text{ or } V_{T-}; V_{CC} = 4.5 \text{ V}$  |      |      |      |      |
|                      |                           | I <sub>O</sub> = -20 μA  | -    | -    | 0.1  | V    |
|                      |                           | I <sub>O</sub> = -4.0 mA   | -    | -    | 0.33 | V    |
| l                    | input leakage current     | $V_{I}$ = GND or $V_{CC}$ ; $V_{CC}$ = 5.5 V   | -    | -    | ±1.0 | μA   |
| I <sub>CC</sub>      | supply current            | $V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A;<br>$V_{CC}$ = 5.5 V                                       | -    | -    | 10.0 | μA   |
| ΔI <sub>CC</sub>     | additional supply current | onal supply current $V_I = V_{CC} - 2.1 V;$<br>$V_{CC} = 4.5 V \text{ to } 5.5 V; I_O = 0 \text{ A}$ |      | -    | 375  | μA   |

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#### **Dual non-inverting Schmitt trigger**

| Symbol                               | Parameter   | Conditions  | Min | Тур | Max  | Unit |  |
|--------------------------------------|---|---|-----|-----|------|------|--|
| T <sub>amb</sub> = -40 °C to +125 °C |   |   |     |     |      |      |  |
| V <sub>OH</sub>                      | HIGH-level output voltage   | $V_{I} = V_{T+} \text{ or } V_{T-}; V_{CC} = 4.5 \text{ V}$ |     |     |      |      |  |
|                                      |   | I <sub>O</sub> = -20 μA                                     | 4.4 | -   | -    | V    |  |
|                                      |   | I <sub>O</sub> = -4.0 mA                                    | 3.7 | -   | -    | V    |  |
| V <sub>OL</sub>                      | LOW-level output voltage  | $V_{I} = V_{T+} \text{ or } V_{T-}; V_{CC} = 4.5 \text{ V}$ |     |     |      |      |  |
|                                      |   | I <sub>O</sub> = -20 μA                                     | -   | -   | 0.1  | V    |  |
|                                      |   | I <sub>O</sub> = -4.0 mA                                    | -   | -   | 0.4  | V    |  |
| l <sub>l</sub>                       | input leakage current   | $V_1 = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$      | -   | -   | ±1.0 | μA   |  |
| I <sub>CC</sub>                      | supply current  | $V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A;<br>$V_{CC}$ = 5.5 V  | -   | -   | 20.0 | μA   |  |
| ΔI <sub>CC</sub>                     | $\Delta I_{CC} \qquad \text{additional supply current} \qquad \begin{array}{l} V_1 = V_{CC} - 2.1 \text{ V}; \\ V_{CC} = 4.5 \text{ V to } 5.5 \text{ V} \end{array}$ |   | -   | -   | 410  | μA   |  |

### 12. Dynamic characteristics

#### **Table 9. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

| Symbol          | Parameter                           | neter Conditions                                |     |     | 25 °C |     | -40 °C to +85 °C |     | -40 °C to +125 °C |     | Unit |
|-----------------|-------------------------------------|---|-----|-----|-------|-----|------------------|-----|-------------------|-----|------|
|                 |                                     |   |     | Min | Тур   | Max | Min              | Мах | Min               | Max |      |
| 74HC2G          | 17                                  |   |     |     |       |     |                  |     |                   |     |      |
| t <sub>pd</sub> | propagation                         | nA to nY; see Fig. 5                            | [1] |     |       |     |                  |     |                   |     |      |
|                 | delay                               | V <sub>CC</sub> = 2.0 V; C <sub>L</sub> = 50 pF |     | -   | 36    | 115 | -                | 140 | -                 | 175 | ns   |
|                 |                                     | V <sub>CC</sub> = 4.5 V; C <sub>L</sub> = 50 pF |     | -   | 12    | 22  | -                | 27  | -                 | 34  | ns   |
|                 |                                     | V <sub>CC</sub> = 6.0 V; C <sub>L</sub> = 50 pF |     | -   | 10    | 18  | -                | 22  | -                 | 28  | ns   |
| t <sub>t</sub>  | transition                          | nY; see <u>Fig. 5</u>                           | [2] |     |       |     |                  |     |                   |     |      |
|                 | time                                | V <sub>CC</sub> = 2.0 V; C <sub>L</sub> = 50 pF |     | -   | 20    | 75  | -                | 95  | -                 | 110 | ns   |
|                 |                                     | V <sub>CC</sub> = 4.5 V; C <sub>L</sub> = 50 pF |     | -   | 7     | 15  | -                | 19  | -                 | 22  | ns   |
|                 |                                     | V <sub>CC</sub> = 6.0 V; C <sub>L</sub> = 50 pF |     | -   | 5     | 13  | -                | 16  | -                 | 19  | ns   |
| C <sub>PD</sub> | power<br>dissipation<br>capacitance | $V_I = GND$ to $V_{CC}$                         | [3] | -   | 10    | -   | -                | -   | -                 | -   | pF   |
| 74HCT2          | G17                                 |   |     |     |       |     |                  | 1   | 1                 | 1   |      |
| t <sub>pd</sub> | propagation                         | nA to nY; see <u>Fig. 5</u>                     | [1] |     |       |     |                  |     |                   |     |      |
|                 | delay                               | V <sub>CC</sub> = 4.5 V; C <sub>L</sub> = 50 pF |     | -   | 21    | 29  | -                | 36  | -                 | 45  | ns   |
| t <sub>t</sub>  | transition                          | nY; see <u>Fig. 5</u>                           | [2] |     |       |     |                  |     |                   |     |      |
| time            | time                                | V <sub>CC</sub> = 4.5 V; C <sub>L</sub> = 50 pF |     | -   | 6     | 15  | -                | 19  | -                 | 22  | ns   |
| C <sub>PD</sub> | power<br>dissipation<br>capacitance | $V_{I} = GND$ to $V_{CC} - 1.5 V$               | [3] | -   | 10    | -   | -                | -   | -                 | -   | pF   |

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ [2]  $t_t$  is the same as  $t_{TLH}$  and  $t_{THL}$ [3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).  $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:  $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

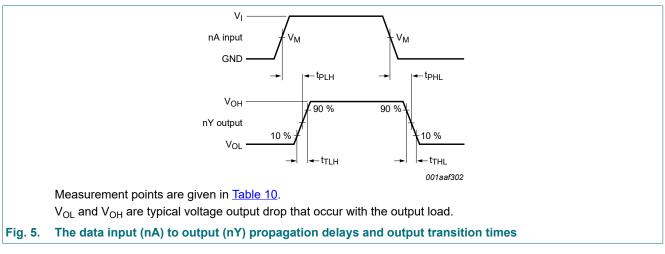
74HC\_HCT2G17

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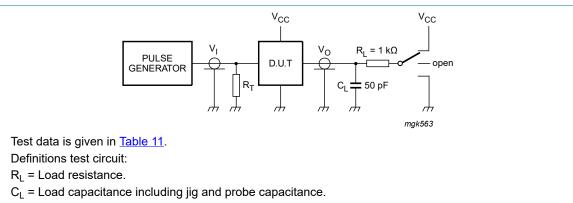
#### Dual non-inverting Schmitt trigger

### 12.1. Waveforms and test circuit



#### Table 10. Measurement points

| Туре      | Input                         | Output                 |                                 |                    |
|-----------|-------------------------------|------------------------|---------------------------------|--------------------|
|           | V <sub>M</sub> V <sub>I</sub> |                        | t <sub>r</sub> = t <sub>f</sub> | V <sub>M</sub>     |
| 74HC2G17  | 0.5V <sub>CC</sub>            | GND to V <sub>CC</sub> | 6.0 ns                          | 0.5V <sub>CC</sub> |
| 74HCT2G17 | 1.3 V                         | GND to 3.0 V           | 6.0 ns                          | 1.3 V              |



 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

#### Fig. 6. Test circuit for measuring switching times

#### Table 11. Test data

| Туре      | Input                  | Test                            |                                     |
|-----------|------------------------|---------------------------------|-------------------------------------|
|           | VI                     | t <sub>r</sub> , t <sub>f</sub> | t <sub>PHL</sub> , t <sub>PLH</sub> |
| 74HC2G17  | GND to V <sub>CC</sub> | 6 ns                            | open                                |
| 74HCT2G17 | GND to 3.0 V           | 6 ns                            | open                                |

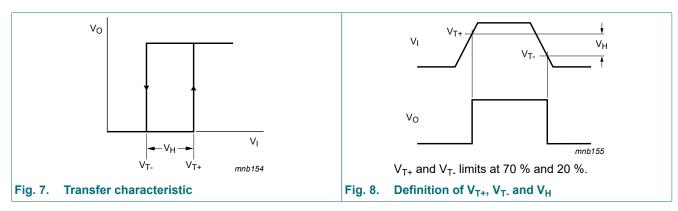
# **13. Transfer characteristics**

#### Table 12. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

| Symbol           | Parameter                              | Conditions   |      | 25 °C |      | -40 °C to +85 °C |      | -40 °C to +125 °C |      | Unit |
|------------------|--|--|------|-------|------|------------------|------|-------------------|------|------|
|                  |  |  | Min  | Тур   | Max  | Min              | Мах  | Min               | Мах  |      |
| 74HC2G           | 17                                     |  |      |       |      | I                | 1    |                   | 1    | _    |
| V <sub>T+</sub>  | positive-going<br>threshold<br>voltage | see <u>Fig. 7, Fig. 8</u>  |      |       |      |                  |      |                   |      |      |
|                  |  | V <sub>CC</sub> = 2.0 V  | 1.00 | 1.18  | 1.50 | 1.00             | 1.50 | 1.00              | 1.50 | V    |
|                  |  | V <sub>CC</sub> = 4.5 V  | 2.30 | 2.60  | 3.15 | 2.30             | 3.15 | 2.30              | 3.15 | V    |
|                  |  | V <sub>CC</sub> = 6.0 V  | 3.00 | 3.46  | 4.20 | 3.00             | 4.20 | 3.00              | 4.20 | V    |
| V <sub>T</sub> . | negative-going<br>threshold<br>voltage | see <u>Fig. 7, Fig. 8</u>  |      |       |      |                  |      |                   |      |      |
|                  |  | V <sub>CC</sub> = 2.0 V  | 0.30 | 0.60  | 0.90 | 0.30             | 0.90 | 0.30              | 0.90 | V    |
|                  |  | V <sub>CC</sub> = 4.5 V  | 1.13 | 1.47  | 2.00 | 1.13             | 2.00 | 1.13              | 2.00 | V    |
|                  |  | V <sub>CC</sub> = 6.0 V  | 1.50 | 2.06  | 2.60 | 1.50             | 2.60 | 1.50              | 2.60 | V    |
| V <sub>H</sub>   | hysteresis<br>voltage                  | V <sub>T+</sub> - V <sub>T-</sub> ; see <u>Fig. 7,</u><br><u>Fig. 8</u> and <u>Fig. 9</u>  |      |       |      |                  |      |                   |      |      |
|                  |  | V <sub>CC</sub> = 2.0 V  | 0.30 | 0.60  | 1.00 | 0.30             | 1.00 | 0.30              | 1.00 | V    |
|                  |  | V <sub>CC</sub> = 4.5 V  | 0.60 | 1.13  | 1.40 | 0.60             | 1.40 | 0.60              | 1.40 | V    |
|                  |  | V <sub>CC</sub> = 6.0 V  | 0.80 | 1.40  | 1.70 | 0.80             | 1.70 | 0.80              | 1.70 | V    |
| 74HCT2           | G17                                    |  |      |       |      |                  |      |                   |      |      |
| V <sub>T+</sub>  | positive-going<br>threshold<br>voltage | see Fig. 7 and Fig. 8  |      |       |      |                  |      |                   |      |      |
|                  |  | V <sub>CC</sub> = 4.5 V  | 1.20 | 1.58  | 1.90 | 1.20             | 1.90 | 1.20              | 1.90 | V    |
|                  |  | V <sub>CC</sub> = 5.5 V  | 1.40 | 1.78  | 2.10 | 1.40             | 2.10 | 1.40              | 2.10 | V    |
| V <sub>T-</sub>  | negative-going<br>threshold<br>voltage | see Fig. 7 and Fig. 8  |      |       |      |                  |      |                   |      |      |
|                  |  | V <sub>CC</sub> = 4.5 V  | 0.50 | 0.87  | 1.20 | 0.50             | 1.20 | 0.50              | 1.20 | V    |
|                  |  | V <sub>CC</sub> = 5.5 V  | 0.60 | 1.11  | 1.40 | 0.60             | 1.40 | 0.60              | 1.40 | V    |
| V <sub>H</sub>   | hysteresis<br>voltage                  | V <sub>T+</sub> - V <sub>T-</sub> ; see <u>Fig. 7,</u><br><u>Fig. 8</u> and <u>Fig. 10</u> |      |       |      |                  |      |                   |      |      |
|                  |  | V <sub>CC</sub> = 4.5 V  | 0.40 | 0.71  | -    | 0.40             | -    | 0.40              | -    | V    |
|                  |  | V <sub>CC</sub> = 5.5 V  | 0.40 | 0.67  | -    | 0.40             | -    | 0.40              | -    | V    |

### 13.1. Waveforms transfer characteristics



74HC\_HCT2G17

2.5

1.0

0.8

0.6

0.4

0.2

0

0

b.  $V_{CC}$  = 4.5 V

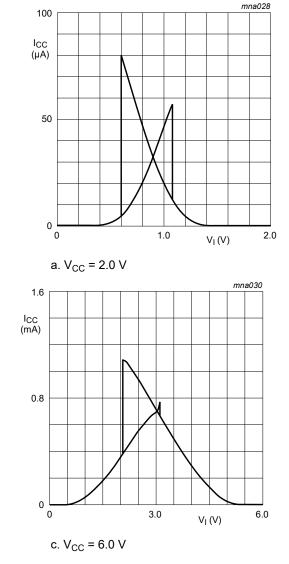
I<sub>CC</sub> (mA)

#### **Dual non-inverting Schmitt trigger**

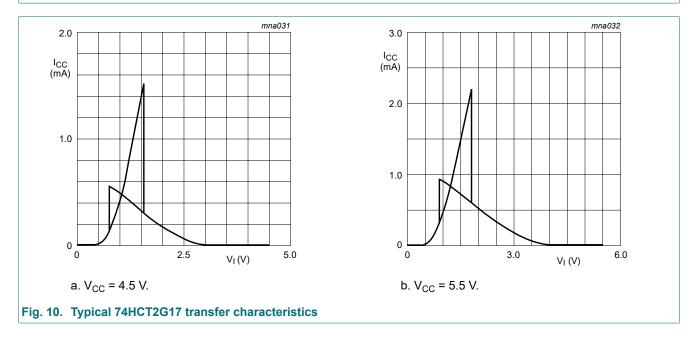
mna029

5.0

 $V_{I}(V)$ 







74HC\_HCT2G17

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### 14. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC} \text{ where:}$ 

 $P_{add}$  = additional power dissipation ( $\mu$ W);

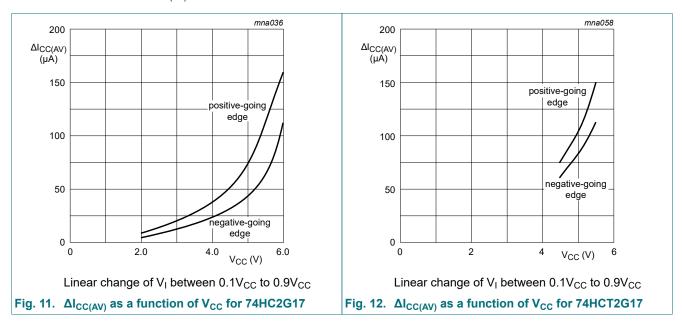
f<sub>i</sub> = input frequency (MHz);

 $t_r$  = input rise time (ns); 10 % to 90 %;

 $t_f$  = input fall time (ns); 90 % to 10 %;

 $\Delta I_{CC(AV)}$  = average additional supply current (µA).

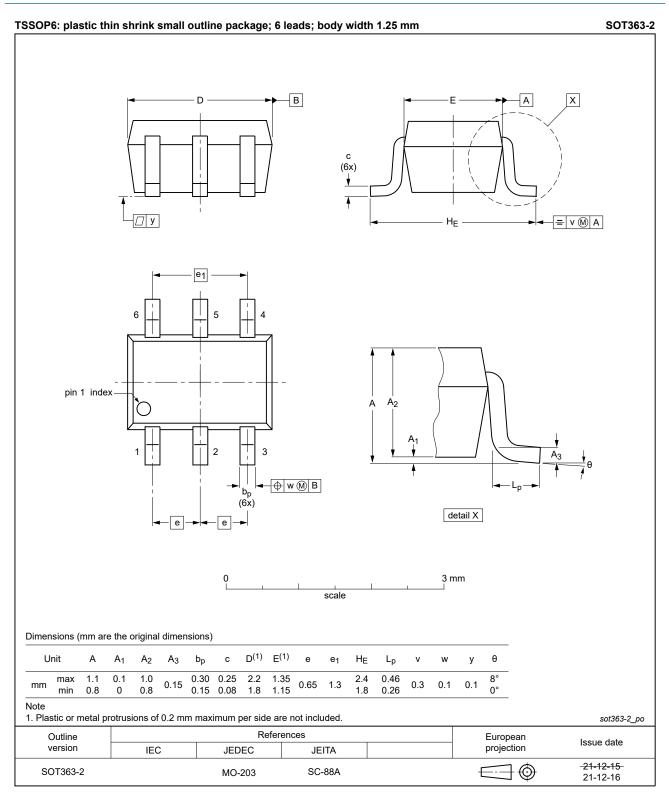
 $\Delta I_{CC(AV)}$  differs with positive or negative input transitions, as shown in Fig. 11 and Fig. 12.



74HC\_HCT2G17

#### Dual non-inverting Schmitt trigger

### 15. Package outline



#### Fig. 13. Package outline SOT363-2 (TSSOP6)

74HC\_HCT2G17

#### **Dual non-inverting Schmitt trigger**

SOT457

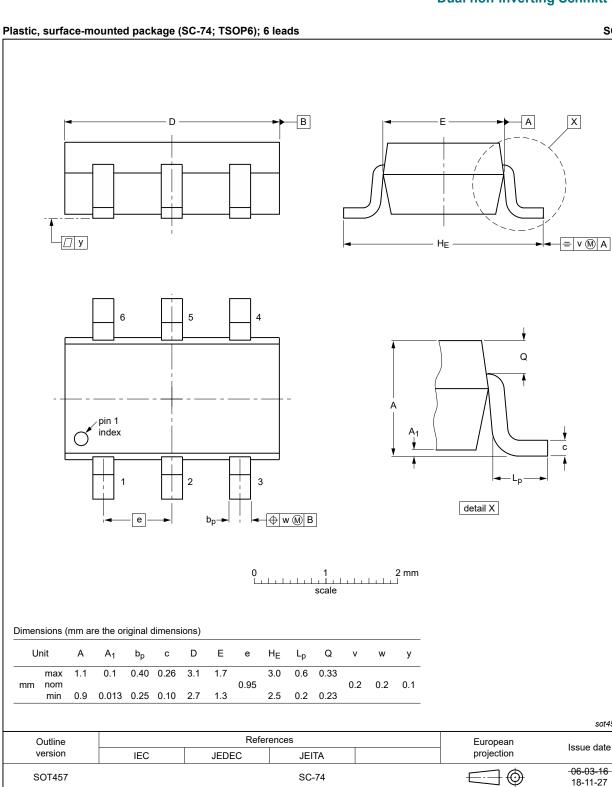


Fig. 14. Package outline SOT457 (SC-74; TSOP6)

sot457\_po

### 16. Abbreviations

| Table 13. Abbreviations |   |  |  |  |
|-------------------------|---|--|--|--|
| Acronym                 | Description                             |  |  |  |
| CMOS                    | Complementary Metal Oxide Semiconductor |  |  |  |
| DUT                     | Device Under Test                       |  |  |  |
| ESD                     | ElectroStatic Discharge                 |  |  |  |
| HBM                     | Human Body Model                        |  |  |  |
| MM                      | Machine Model                           |  |  |  |
| TTL                     | Transistor-Transistor Logic             |  |  |  |

# 17. Revision history

#### Table 14. Revision history

| Document ID      | Release date  | Data sheet status   | Change notice  | Supersedes  |
|------------------|---|---|--|---|
| 74HC_HCT2G17 v.2 | 20220202  | Product data sheet  | -  | 74HC_HCT2G17 v.1  |
| Modifications:   | guidelines o<br>Legal texts f<br>Package SC<br><u>Section 1</u> ar<br><u>Section 9</u> : D<br><u>Section 11</u> : | of this data sheet has been<br>f Nexperia.<br>nave been adapted to the r<br>DT363 (SC-88) changed to<br>nd <u>Section 2</u> updated.<br>Derating values for P <sub>tot</sub> total<br>V <sub>OH</sub> and V <sub>OL</sub> conditions co<br>kage outline drawing SOT | new company nan<br>SOT363-2 (TSSC<br>I power dissipation<br>rrected to V <sub>I</sub> = V <sub>T</sub> | ne where appropriate.<br>DP6).<br>n updated.<br><sub>+</sub> or V <sub>T</sub> (Errata) |
| 74HC_HCT2G17 v.1 | 20061006  | Product data sheet  | -  | -   |

# 18. Legal information

#### Data sheet status

| Document status<br>[1][2]         | Product<br>status [3] | Definition  |
|-----------------------------------|-----------------------|---|
| Objective [short]<br>data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short]<br>data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet     | Production            | This document contains the product specification.                                     |

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- [2] The term 'short data sheet' is explained in section "Definitions".
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